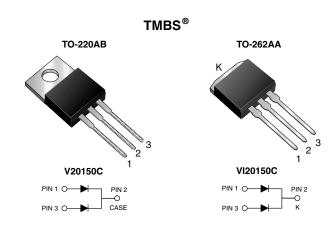
New Product



Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.59$ V at $I_F = 5$ A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 10 A					
V _{RRM}	150 V				
I _{FSM}	120 A				
V_F at $I_F = 10$ A	0.69 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads. solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test. HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	V20150C	VI20150C	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	150		V		
Maximum average forward rectified current (fig. 1)	per device	I	20		٨		
	per diode	IF(AV)	1	0	A		
Peak forward surge current 8.3 ms single half sine-w superimposed on rated load per diode	I _{FSM}	120		А			
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to	+ 150	°C		

RoHS COMPLIANT HALOGEN FREE

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.79	-	V		
	I _F = 10 A			1.05	1.20			
	I _F = 5 A	- T _A = 125 °C		0.59	-			
	I _F = 10 A			0.69	0.75			
Reverse current per diode	V _B = 100 V	$T_{A} = 25 \text{°C}$	I _R (2)	1.3	-	μA		
	v _R = 100 v	T _A = 125 °C		1.2	-	mA		
	$V_{\rm B} = 150 {\rm V}$	T _A = 25 °C		-	150	μA		
		T _A = 125 °C		3	15	mA		

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL V20150C VI20150C		UNIT		
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	2.8		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20150C-M3/4W	1.88	4W	50/tube	Tube		
TO-262AA	VI20150C-M3/4W	1.45	4W	50/tube	Tube		
TO-220AB	V20150CHM3/4W (1)	1.88	4W	50/tube	Tube		
TO-262AA	VI20150CHM3/4W ⁽¹⁾	1.45	4W	50/tube	Tube		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

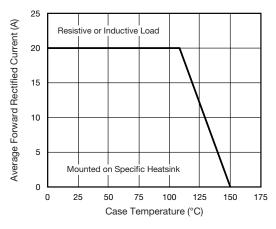


Fig. 1 - Maximum Forward Current Derating Curve

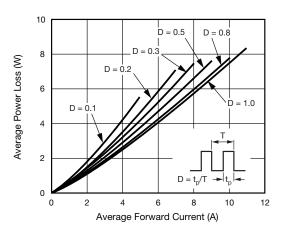


Fig. 2 - Forward Power Loss Characteristics Per Diode

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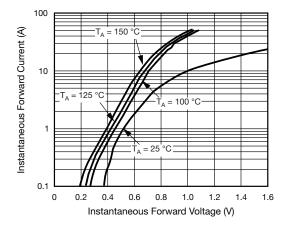


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

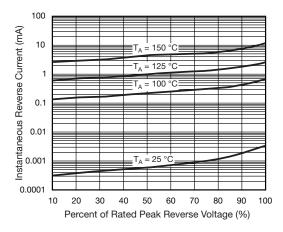


Fig. 4 - Typical Reverse Characteristics Per Diode

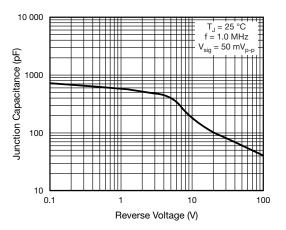


Fig. 5 - Typical Junction Capacitance Per Diode

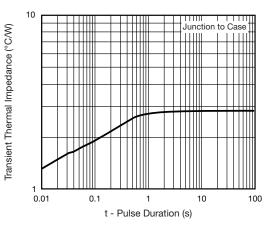


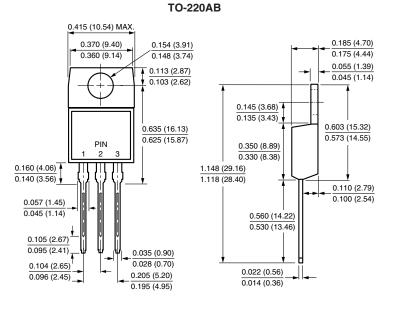
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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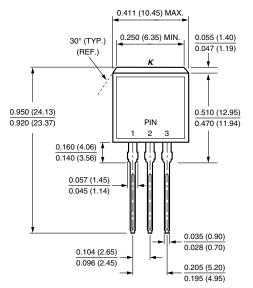
V20150C, VI20150C

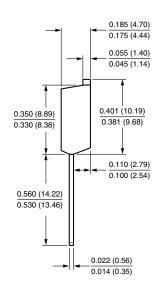
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA







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